

LEDIST OPTOELECTRONICS CO., LTD

Data sheet for LA-205711BWB

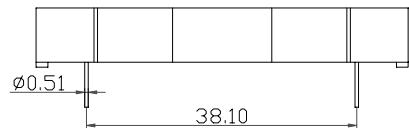
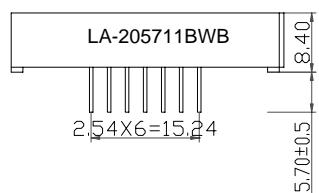
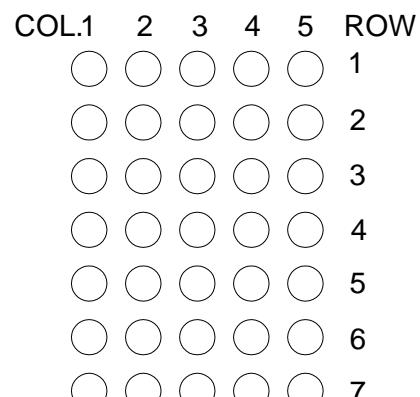
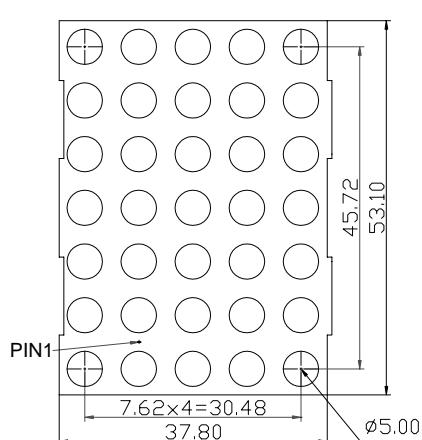
■ Features:

- Low power consumption
- High intensity and solid state reliability
- Continuous and uniform segment
- Industrial standard size, IC compatible

■ Description:

- 5×7 dot matrix display, 5.0mm dot and 7.62mm pitch
- Emitting color: High blue, InGaN
- Black face, White diffused epoxy
- Common anode

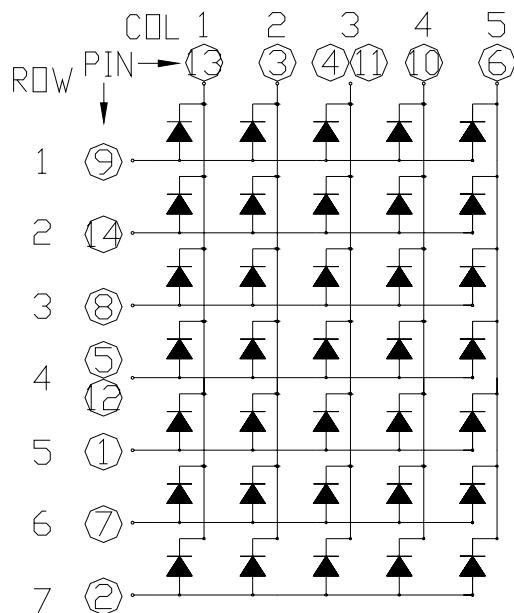
■ Package Dimensions:



Notes:

1. All dimensions are in millimeters(inches)
2. Tolerance is 0.25mm(0.01") unless otherwise noted
3. Above specifications may be changed without notice

■ Internal Circuit Diagram:



■ Absolute maximum ratings at Ta = 25 : :

Parameter	Max	Unit
Reverse Voltage	5	V
Forward Current	25	mA
Operating Temperature	-40 to + 85	°C
Storage Temperature	-40 to + 85	°C
Soldering Temperature	260 ± 5(less than 5 sec.)	°C
Power Consumption	60	mW

■ Electrical Characteristics at TA=25°C:

Parameter	Symbol	Min	Typ	Max	Unit	Test condition
Luminous Intensity Per Segment	I _v	—	15	—	mcd	IF=10mA
Dominant Wavelength	λ _d	—	463	—	nm	IF=20mA
Spectrum Radiation Bandwidth	Δλ	—	26	—	nm	IF=20mA
Forward Voltage Per Segment	V _f	—	3.3	3.7	V	IF=20mA
Reverse Current Per Segment	I _r	—	—	100	μ A	VR =5V